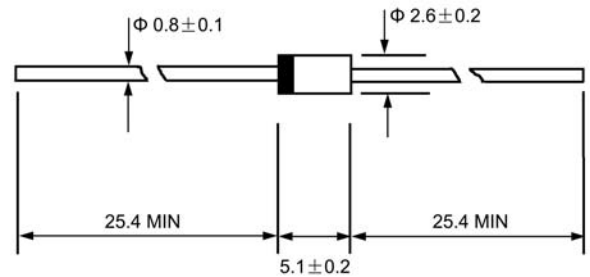




### DO - 41



Dimensions in millimeters

## Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, Isopropanol and similar solvents

## Mechanical Data

- ◇ Case: JEDEC DO-41, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting: Any

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		EG1Y	EG1Z	EG1	EG1A	UNITS
Maximum peak repetitive reverse voltage	$V_{RRM}$	70	200	400	600	V
Maximum RMS voltage	$V_{RMS}$	49	140	280	420	V
Maximum DC blocking voltage	$V_{DC}$	70	200	400	600	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	1.1	0.8		0.6	A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	$I_{FSM}$	30.0	15.0		10.0	A
Maximum instantaneous forward voltage @ $I_F=I_{F(AV)}$	$V_F$	1.2	1.7	1.8	2.0	V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	$I_R$	100.0 500.0	50.0 300.0		100.0 500.0	$\mu\text{A}$
Maximum reverse recovery time (Note1)	$t_{rr}$	50				ns
Typical junction capacitance (Note2)	$C_J$	20			15	pF
Typical thermal resistance (Note3)	$R_{\theta JL}$	60				$^\circ\text{C/W}$
Operating junction temperature range	$T_J$	- 55 ----- + 150				$^\circ\text{C}$
Storage temperature range	$T_{STG}$	- 55 ----- + 150				$^\circ\text{C}$

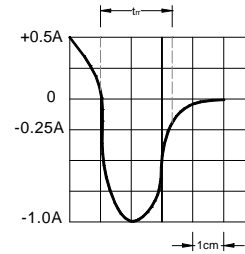
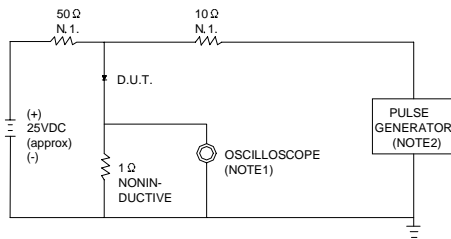
NOTE: 1. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient.

## Ratings AND Characteristic Curves

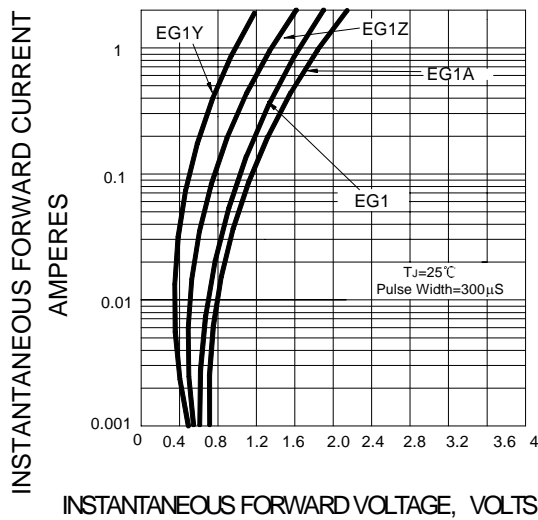
**FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



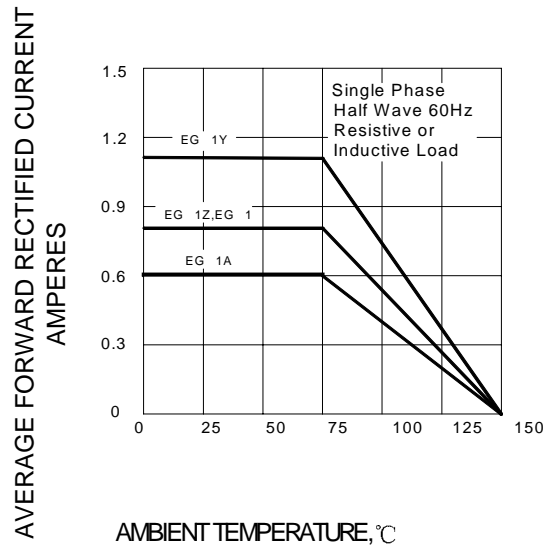
NOTES:1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ, 22pF.  
2.RISE TIME = 10ns MAX.SOURCE IMPEDANCE = 50 Ω.

SET TIME BASE FOR 10/20 ns/cm

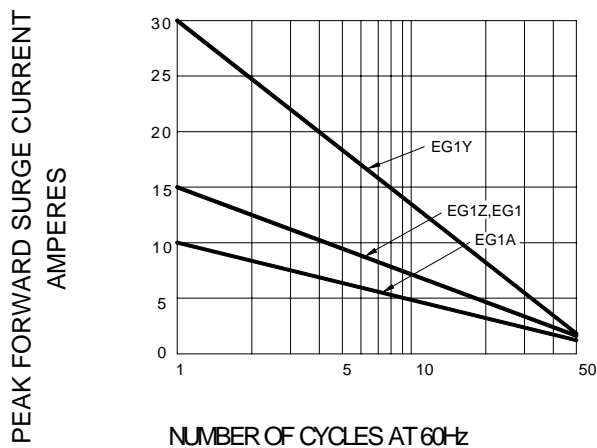
**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.3 – FORWARD DERATING CURVE**



**FIG.4 – PEAK FORWARD SURGE CURRENT**



**FIG.5 – TYPICAL JUNCTION CAPACITANCE**

